Diode Semiconductor Device - Page 1 of 1



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	nclosure Material:
C	Glass and metal
C	Overall Length:
С	0.453 inches
C	Overall Diameter:
С	0.687 inches
N	Nounting Facility Quantity:
1	
N	Nounting Method:
T	Threaded stud
F	eatures Provided:
ŀ	lermetically sealed case
T	hread Size:
С	0.250 inches
S	Semiconductor Material:
S	Silicon
٧	oltage Rating In Volts Per Characteristic:
1	00.0 reverse voltage, peak
C	Current Rating Per Characteristic:
1	0.00 amperes average forward current averaged over a full 60-hz cycle
N	Aximum Operating Tempurature Per Measurement Point:
1	75.0 degrees celsius ambient air
T	hread Series Designator:
ι	Jnf
T	erminal Type And Quantity:
2	tab, solder lug
S	Shelf Life:
Ν	l/a
ι	Init Of Measure:
-	-
C	Demilitarization:
Ν	lo

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